Advance Information 4.7 pF Passive Tunable Integrated Circuits (PTIC)

Introduction

ON Semiconductor's PTICs have excellent RF performance and power consumption, making them suitable for any mobile handset or radio application. The fundamental building block of our PTIC product line is a tunable material called ParaScanTM, based on Barium Strontium Titanate (BST). PTICs have the ability to change their capacitance from a supplied bias voltage generated by the Control IC. The 4.7 pF PTICs are available as wafer-level chip scale packages (WLCSP) and in QFN packages for easy mounting directly on printed circuit boards.

Key Features

- High Tuning Range and Operation up to 20 V
- Usable Frequency Range: from 700 MHz to 2.7 GHz
- High Quality Factor (Q) for Low Loss
- High Power Handling Capability
- Compatible with PTIC Control IC TCC-103
- WLCSP Package: 0.722 x 1.179 x 0.611 mm (12 pillar)
- QFN Package: 1.200 x 1.600 x 0.950 mm
- QFN: MSL-2 Moisture Sensitivity Level (per J-STD-020)
- Pb–Free and RoHS Compliant

Typical Applications

- Multi-band, Multi-standard, Advanced and Simple Mobile Phones
- Tunable Antenna Matching Networks
- Tunable RF Filters
- Active Antennas

This document contains information on a new product. Specifications and information herein are subject to change without notice.



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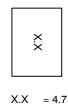


WLCSP 12 pillar CASE TBD

QFN







FUNCTIONAL BLOCK DIAGRAM

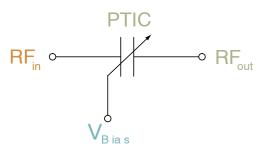


Figure 1. PTIC Functional Block Diagram

ORDERING INFORMATION

| Device | Package | Shipping |
|--------------|--------------------|-------------------|
| TCP-3047H-DT | WLCSP (Pb-Free) | 5000 Units / Reel |
| TCP-3047H-QT | QFN (Pb-Free) | 5000 Units / Reel |

For detailed ordering information, including part number definition and capacitance (pF) see the package dimensions section on page 7 of this datasheet.

TYPICAL SPECIFICATIONS

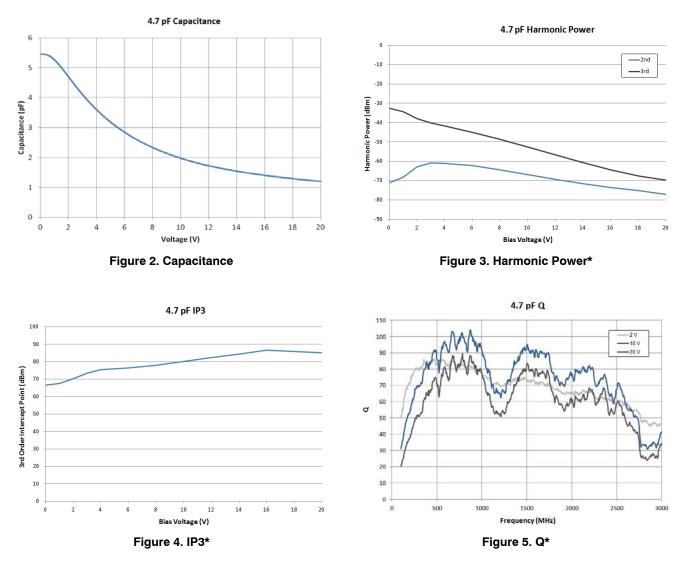
Representative Performance Data at 25°C

Table 1. PERFORMANCE DATA

| Parameter | Min | Тур | Max | Units |
|---|------|------|------|-------|
| Operating Bias Voltage | 2 | | 20 | V |
| Capacitance (V _{bias} = 2 V) | 4.23 | 4.70 | 5.17 | pF |
| Capacitance (V _{bias} = 20 V) | 1.18 | 1.2 | 1.30 | pF |
| Tuning Range (2 V - 20 V) | 3.4 | 4 | 4.2 | |
| Tuning Range (20 V - 2 V) | | 3.6 | | |
| Leakage Current (WLCSP) | | | 2 | μΑ |
| Operating Frequency | 700 | | 2700 | MHz |
| Quality Factor @ 700 MHz, 10 V | | 90 | | |
| Quality Factor @ 2.4 GHz, 10 V | | 60 | | |
| IP3 (V _{bias} = 2 V) ^[1,3] | | 70 | | dBm |
| IP3 (V _{bias} = 20 V) ^[1,3] | | 85 | | dBm |
| 2nd Harmonic ($V_{bias} = 2 V$) ^[2,3] | | -65 | | dBm |
| 2nd Harmonic ($V_{bias} = 20 \text{ V}$) ^[2,3] | | -80 | | dBm |
| 3rd Harmonic (V _{bias} = 2 V) ^[2,3] | | -40 | | dBm |
| 3rd Harmonic ($V_{bias} = 20 \text{ V}$) ^[2,3] | | -70 | | dBm |
| Transition Time (Cmin \rightarrow Cmax) ^[4] | | 80 | | μs |
| Transition Time (Cmax \rightarrow Cmin) ^[4] | | 70 | | μs |

1. $f_1 = 850 \text{ MHz}$, $f_2 = 860 \text{ MHz}$, Pin 25 dBm/Tone 2. 850 MHz, Pin +34 dBm 3. IP3 and Harmonics are measured in the shunt configuration in a 50 Ω environment 4. RF_{IN} and RF_{OUT} are both connected to DC ground

Representative performance data at 25°C for 4.7 pF WLCSP Package



*The data shown is based on the TCP-1047N device performance, for reference only. The TCP-3047H performance data will be available in the Production Datasheet.

Table 2. ABSOLUTE MAXIMUM RATINGS

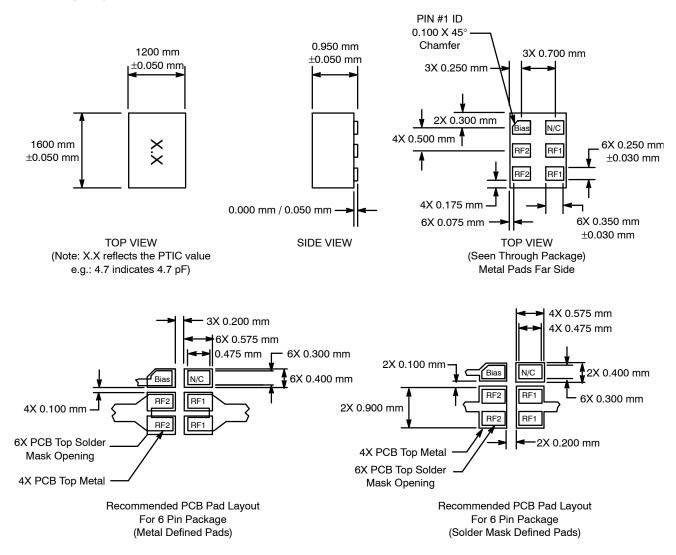
| Parameter | Rating | Units |
|-----------------------------|--------------------------------------|-------|
| Input Power | +40 | dBm |
| Bias Voltage | +25 (Note 5) | V |
| Operating Temperature Range | -30 to +85 | °C |
| Storage Temperature Range | -55 to +125 | °C |
| ESD – Human Body Model | Class 1A JEDEC HBM Standard (Note 6) | |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

5. WLCSP: Recommended Bias Voltage not to exceed 20 V

6. Class 1A defined as passing 250 V, but may fail after exposure to 500 V ESD pulse

PACKAGE INFORMATION



QFN Package Layout and Dimensional Information



Wafer Level Chip Scale Package (WLCSP) Layout and Dimensional Information

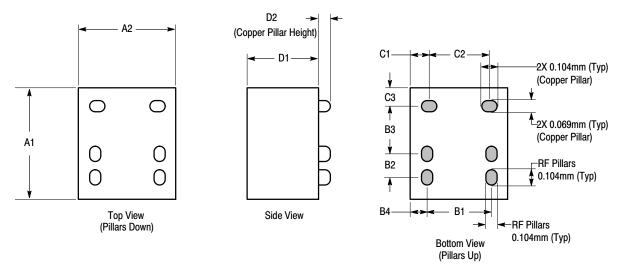




Table 3. PACKAGE DIMENSIONS

(All dimensions are in millimeters)

| WLCSP * | DIM | Nominal | Max | Device |
|---------|-----|---------|-----|------------------|
| 8P | A1 | 0.879 | | 1.2, 2.7 pF |
| 10P | A1 | 1.029 | | 3.9 pF |
| 12P | A1 | 1.179 | | 4.7, 5.6, 8.2 pF |
| 14P | A1 | 1.329 | | |
| ALL | A2 | 0.722 | | |
| ALL | B1 | 0.460 | | |
| ALL | B2 | 0.150 | | |
| ALL | B3 | 0.300 | | |
| ALL | B4 | 0.130 | | |
| ALL | C1 | 0.148 | | |
| ALL | C2 | 0.425 | | |
| ALL | C3 | 0.130 | | |
| ALL | D1 | 0.530 | | |
| ALL | D2 | 0.081 | | |

Top View Recommended PCB Pad Layout (Metal Defined Pad)

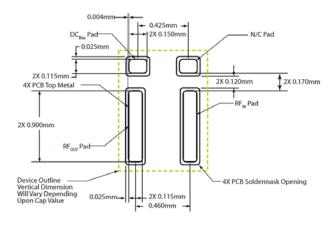


Figure 8. Recommended Pad Layout

*Total number of pillars

ASSEMBLY CONSIDERATIONS AND REFLOW PROFILE

The following assembly considerations should be observed:

Cleanliness

These chips should be handled in a clean environment.

Electro-static Sensitivity

ON Semiconductor's PTICs are ESD Class 1A sensitive. The proper ESD handling procedures should be used.

Mounting

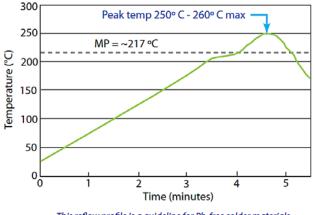
The WLCSP PTIC is fabricated for Flip Chip solder mounting. Connectivity to the RF and Bias terminations on the PTIC die is established through copper pillar posts (53 μ m nominal height) topped with lead-free SAC351 solder caps (28 μ m nominal height). The PTIC die is RoHS-compliant and compatible with lead-free soldering profile.

Post-reflow Cleaning

Use of ultrasonic cleaning is not recommended for pillared devices as it may lead to premature fatigue failure of the pillars.

Molding

The PTIC die is compatible for over-molding or under-fill.



This reflow profile is a guideline for Pb-free solder materials. Adjustments to this profile are necessary based on specific process requirements and board size, thickness and density. Not to exceed 260° C for 5 seconds.

Figure 9. Reflow Profile

PART NUMBER DEFINITION

Example: TCP-3047H-DT

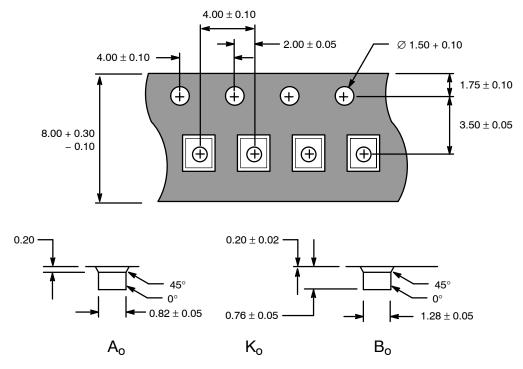
| ТСР | | - | 30 | 47 | н | - | D | т |
|-------------------|--|---|------------------------------|--|------------------------|---|-----------------------------------|---------|
| Product Family | Process Status | | Process Generation | <u>Capacitor</u> <u>Value</u> | Tuning | | <u>Package /</u> <u>Format</u> | Packing |
| ТСР | "blank" = Production X = Pilot Production S = Special/Custom P = Prototype | - | 10 = Gen 1.0 30 = Gen 3.0 | 12 = 1.2 pF 27 = 2.7 pF 39 = 3.9 pF 47 = 4.7 pF 56 = 5.6 pF 82 = 8.2 pF | N = Normal H = High | _ | D = WLCSP Q = QFN | T = T&R |

Table 4. PART NUMBERS

| | Сарас | itance | |
|--------------|-------|--------|-----------------|
| Part Number | 2 V | 20 V | Package* |
| TCP-3047H-DT | 4.70 | 1.2 | 12-Pillar WLCSP |
| TCP-3047H-QT | 4.70 | 1.2 | 6-Pin QFN |

*See PTIC package dimensions on page 5

TAPE & REEL DIMENSIONS



NOTE: The reel size is 13"

Figure 10. 12 Pillar WLCSP Carrier Tape Drawing

TAPE & REEL DIMENSIONS (Cont'd)

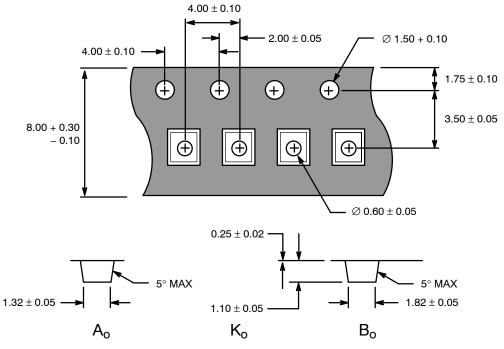


Figure 11. QFN Carrier Tape Drawing

Table 5. POCKET DIMENSION

| Pocket Dimension (mm) | | | Unit Dimension (mm) | | | | |
|-----------------------|---------------|------|---------------------|---|---------------|------|------|
| | Spec | Max | Min | | Spec | Max | Min |
| Ao | 1.32 ± 0.05 | 1.37 | 1.27 | А | 1.2 ± 0.05 | 1.25 | 1.15 |
| Во | 1.82 ± 0.05 | 1.87 | 1.77 | В | 1.6 ± 0.05 | 1.65 | 1.55 |
| Ko | 1.1 ± 0.05 | 1.15 | 1.05 | К | 0.95 ± 0.05 | 1.00 | 0.90 |

NOTE: The reel size is 7"

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